

## UNITED STATES PATENT AND TRADEMARK OFFICE



UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

DATE MAILED: 06/18/2004

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/653,411	08/31/2000	Whonchee Lee	M4065.0361/P361	5349
24998	7590 06/18/2004		EXAMINER	
	SHAPIRO MORIN	NGUYEN, JOSEPH H		
2101 L STREET NW WASHINGTON, DC 20037-1526			ART UNIT	PAPER NUMBER
			2815	

Please find below and/or attached an Office communication concerning this application or proceeding.

				r~			
		Application No.	Applicant(s)				
		09/653,411	LEE ET AL.				
	Office Action Summary	Examin r	Art Unit				
		Joseph Nguyen	2815				
Period fo	- The MAILING DATE of this communic r Reply	ation appears on the cover sh	eet with the correspond nce ad	ddress			
THE N - Exten after S - If the - If NO - Failur Any re earne	DRTENED STATUTORY PERIOD FO MAILING DATE OF THIS COMMUNIC sions of time may be available under the provisions of SIX (6) MONTHS from the mailing date of this commu period for reply specified above is less than thirty (30) period for reply is specified above, the maximum state to reply within the set or extended period for reply weaply received by the Office later than three months after the provided part of the provided part	ATION.  37 CFR 1.136(a). In no event, however, nication. days, a reply within the statutory minimur tory period will apply and will expire SIX (III), by statute, cause the application to be	may a reply be timely filed  n of thirty (30) days will be considered time 6) MONTHS from the mailing date of this come ABANDONED (35 U.S.C. § 133).				
Status							
1)⊠	Responsive to communication(s) filed	on <u>06 February 2004</u> .					
2a) <u></u> □	This action is <b>FINAL</b> . 2b)⊠ This action is non-final.						
•	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Dispositi	on of Claims						
5)□ 6)⊠ 7)□	Claim(s) 39-51 is/are pending in the a 4a) Of the above claim(s) is/are Claim(s) is/are allowed. Claim(s) 39-51 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restricti	e withdrawn from consideration					
Applicati	on Papers						
9) 🗌 -	The specification is objected to by the	Examiner.					
10)🛛 ີ	The drawing(s) filed on <u>31 August 200</u>	$\underline{00}$ is/are: a) $oxtime 2$ accepted or b)	objected to by the Examin	er.			
	Applicant may not request that any object						
	Replacement drawing sheet(s) including t The oath or declaration is objected to						
Priority u	nder 35 U.S.C. § 119						
a)[	Acknowledgment is made of a claim for All b) Some * c) None of:  1. Certified copies of the priority of the priority of the priority of the certified copies of the priority of the certified copies of the certified copies of application from the Internation the the attached detailed Office actions	ocuments have been receive locuments have been receive f the priority documents have al Bureau (PCT Rule 17.2(a)	d. d in Application No been received in this Nationa ).	I Stage			
Attachment	(s)	_					
	e of References Cited (PTO-892)		erview Summary (PTO-413)				
3) 🛛 Inform	e of Draftsperson's Patent Drawing Review (PT nation Disclosure Statement(s) (PTO-1449 or P · No(s)/Mail Date <u>02/06/2004</u> .	TO/SB/08) 5) Not	er No(s)/Mail Date ice of Informal Patent Application (PT er:	<sup>·</sup> O-152)			

## **DETAILED ACTION**

Page 2

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 39- 47, 49-50 are rejected under 35 U.S.C. 102(b) as being anticipated by Lee et al (2001/0025976 A1).

Regarding claim 39, Lee et al discloses on figure 5 a semiconductor device comprising a substrate 31 and at least one electron mechanically polished metal layer 53 formed over said substrate 31, said electro mechanically polished metal layer's surface has been electro-mechanically polished against a second surface while submersed in an electric bath.

It should be noted that the term "electro-mechanical polished against a second surface while submersed in an electric bath" merely recites product by process and does not structurally distinguish the metal layer from the structure taught by Lee et al.

Regarding claim 40, Lee et al disclose on figure 5 the metal layer 53 comprises at least one metal selected from the group consisting of noble metals, noble metal alloys, refractory metals and refractory metal alloys.

Regarding claim 41, Lee et al disclose on figure 5 the device comprises a capacitor with at least one electro mechanical polished metal layer 53.

Regarding claim 42, Lee et al disclose on figure 5 the electro-mechanical polished metal layer 53 is bottom electrode of said capacitor.

Regarding claim 43, Lee et al disclose on figure 5 a semiconductor device comprising a bottom electrode 53 formed over a substrate 31; an insulating layer 55 formed over the bottom electrode; and a top electrode 57 formed over the insulating layer 55, wherein at least one electrode surface comprises an electro mechanically polished surface that has been electro-mechanically polished against a second surface while submersed in an electric bath.

It should be noted that the term "electro-mechanical polished against a second surface while submersed in an electric bath" merely recites product by process and does not structurally distinguish the metal layer from the structure taught by Lee et al.

Regarding claim 44, Lee et al disclose on figure 5 the capacitor is a MIM capacitor.

Regarding claim 45, Lee et al disclose on figure 5 at least one electrode 53 comprises a metal selected from the group consisting of noble metals, noble metal alloys, refractory metals and refractory metal alloys.

Regarding claim 46, Lee et al disclose on figure 5 at least one electrode surface is a surface of the bottom electrode 53.

Regarding claim 47, Lee et al disclose on figure 5 the bottom electrode 53 comprises a platinum electrode.

Regarding claim 49, Lee et al discloses on figure 5 a semiconductor device comprising a substrate 31; and at least one electro-mechanically polished metal layer 53 consisting of a noble metal formed.

Regarding claim 50, Lee et al discloses on figure 5 a semiconductor device comprising a bottom electrode 53 formed over a substrate 31; an insulating layer 55 formed over said bottom electrode; and a top electrode 57 formed over said insulating layer, wherein at least one electrode surface comprises an electro mechanically polished noble metal surface.

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 48 and 51 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al in view of Sandhu et al.

Regarding claims 48 and 51, Lee et al disclose substantially all the structure set forth in the claimed invention except a memory device electrically coupled to a processor. However, Sandhu et al disclose on figure 20 a memory device 1100 electrically coupled to a processor. In view of such teaching, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify Lee et al

Application/Control Number: 09/653,411 Page 5

Art Unit: 2815

by having a memory device electrically coupled to a processor for the purpose of

improving the performance of the integrated circuits.

Conclusion

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Joseph Nguyen whose telephone number is (571) 272-

1734. The examiner can normally be reached on Monday-Friday, 7:30 am- 4:30 pm

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for

the organization where this application or proceeding is assigned is (703) 872-9306 for

regular communications.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is (703) 308-

0956.

JN

June 17, 2004

JEROME JACKSON BRIMARY EXAMINER